MMBTA92LT1

Preferred Device

High Voltage Transistor

PNP Silicon

Features

• Pb–Free Package May be Available. The G–Suffix Denotes a Pb–Free Lead Finish

MAXIMUM RATINGS

Rating	Symbol	MMBTA92	Unit
Collector-Emitter Voltage	V _{CEO}	-300	Vdc
Collector-Base Voltage	V _{CBO}	-300	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current – Continuous	Ι _C	-500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit	
Total Device Dissipation FR–5 Board, (Note 1) $T_A = 25^{\circ}C$ Derate above 25°C	P _D	225 1.8	mW mW/°C	
		1.0		
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W	
Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^{\circ}C$	P _D	300	mW	
Derate above 25°C		2.4	mW/°C	
Thermal Resistance, Junction-to-Ambi- ent	R_{\thetaJA}	417	°C/W	
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C	

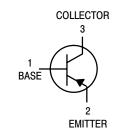
1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in.

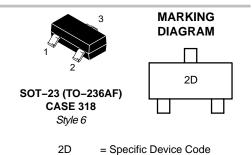
2. Alumina = 0.4 x 0.3 x 0.024 in. 99.5% alumina.



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ORDERING INFORMATION			
Device	Package	Shipping [†]	
MMBTA92LT1	SOT-23	3000 / Tape & Reel	
MMBTA92LT1G	SOT-23	3000 / Tape & Reel	
MMBTA92LT3	SOT-23	10000 / Tape & Reel	

⁺For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

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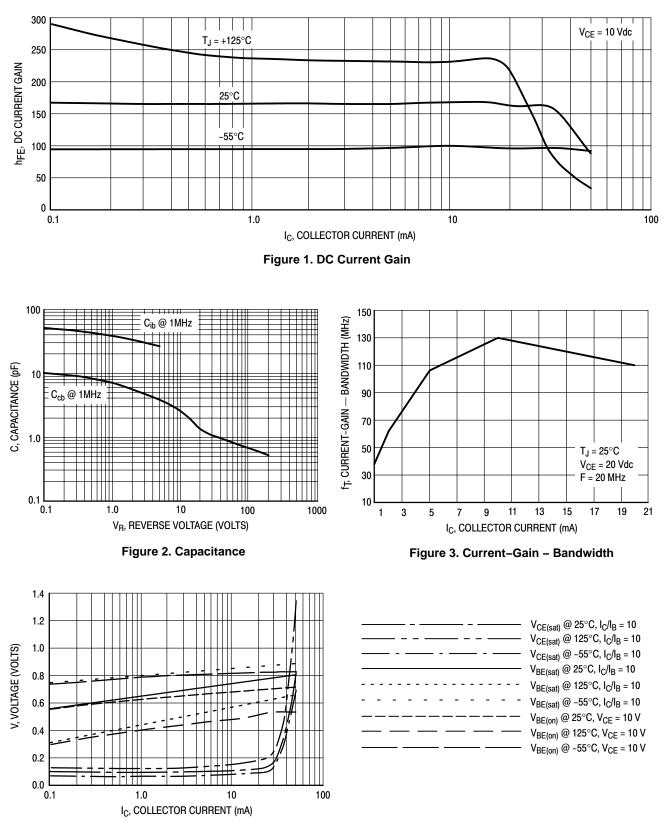
MMBTA92LT1

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS	·			
Collector – Emitter Breakdown Voltage (Note 3) $(I_C = -1.0 \text{ mAdc}, I_B = 0)$	V _{(BR)CEO}	-300	_	Vdc
Collector – Base Breakdown Voltage ($I_C = -100 \ \mu Adc, I_E = 0$)	V _{(BR)CBO}	-300	_	Vdc
Emitter – Base Breakdown Voltage ($I_E = -100 \ \mu Adc, I_C = 0$)	V _{(BR)EBO}	-5.0	-	Vdc
Collector Cutoff Current ($V_{CB} = -200 \text{ Vdc}, I_E = 0$)	Ісво	_	-0.25	μAdc
Emitter Cutoff Current ($V_{EB} = -3.0$ Vdc, $I_C = 0$)	I _{EBO}	_	-0.1	μAdc
ON CHARACTERISTICS (Note 3)				
$ \begin{array}{l} \text{DC Current Gain} \\ (I_{C} = -1.0 \text{ mAdc}, \text{V}_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -10 \text{ mAdc}, \text{V}_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -30 \text{ mAdc}, \text{V}_{CE} = -10 \text{ Vdc}) \end{array} $	h _{FE}	25 40 25		_
Collector – Emitter Saturation Voltage ($I_C = -20$ mAdc, $I_B = -2.0$ mAdc)	V _{CE(sat)}	-	-0.5	Vdc
Base-Emitter Saturation Voltage ($I_C = -20$ mAdc, $I_B = -2.0$ mAdc)	V _{BE(sat)}	_	-0.9	Vdc
SMALL-SIGNAL CHARACTERISTICS	·			
Current-Gain – Bandwidth Product ($I_C = -10$ mAdc, $V_{CE} = -20$ Vdc, f = 100 MHz)	f _T	50	-	MHz
Collector–Base Capacitance ($V_{CB} = -20$ Vdc, $I_E = 0$, f = 1.0 MHz)	C _{cb}	_	6.0	pF

3. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

MMBTA92LT1





PACKAGE DIMENSIONS

SOT-23 (TO-236)

CASE 318-08 **ISSUE AH**

S в

С

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G

- NOTES: DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH. 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE
- MATERIAL 4. 318-03 AND -07 OBSOLETE, NEW STANDARD 318-08.

	INCHES		MILLIN	ETERS
DIM	MIN	MAX	MIN	MAX
Α	0.1102	0.1197	2.80	3.04
В	0.0472	0.0551	1.20	1.40
С	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
Н	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
Κ	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
٧	0.0177	0.0236	0.45	0.60



2 EMITTER

COLLECTOR 3.

SOLDERING FOOTPRINT*

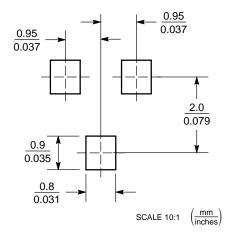


Figure 5. SOT-23

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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